

NCL30167

Power Factor Corrected LED Boost Switching Regulator

The NCL30167 high power factor boost PWM switching regulator is designed to regulate the average current through a string of LEDs. The circuit operates in Critical Conduction Mode (CrM) based on a proven constant on-time control scheme to achieve near unity power factor. In addition to regulating a constant current, the switching regulator is optimized to support leading and trailing edge phase dimming applications. When a dimmer is detected on the AC input, an internal voltage reference of the current regulation loop adjusts the current level based on the dimmer conduction angle so the current through the LED string has a desired value based on a programmed dimming curve. The shape of the dimming curve is intended to emulate the response of an incandescent bulb while achieving NEMA SSL6 and NEMA SSL7A recommendations.

A cascoded configuration supports biasing the controller during operation and eliminates the need for an auxiliary winding to provide bias power. A robust suite of protection features are included to ensure proper handling of expected fault conditions without the need for extra circuitry and a dedicated thermal fold-back input proves gradually reduction of the current above a user defined set-point.

Features

- Near-Unity Power Factor
- Critical Conduction Mode (CrM)
- Constant On-time Control
- Accurate Current Regulation ($\pm 2\%$ Typical)
- Compatible with Leading and Trailing Edge Phase Controlled Dimmers
- Fast Startup Time (< 100 ms Typical)
- Integrated ZCD Detection
- User Programmable Thermal Current Fold-back
- V_{CC} Operation up to 20 V
- This Device is Pb-Free and is RoHS Compliant

Safety Features

- Output Overvoltage Protection
- Cycle-by-Cycle Current Limiting
- V_{CC} UVLO

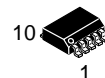
Typical Applications

- LED Bulbs
- LED Downlights
- LED Light Engines
- LED Modules



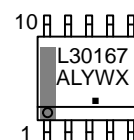
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SOIC-10
CASE 751BQ

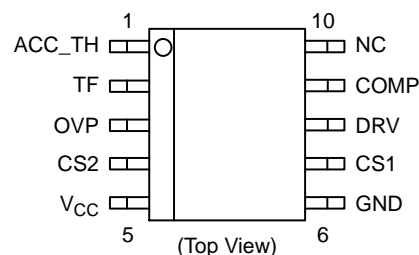
MARKING DIAGRAM



L30167 = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
■ = Pb-Free Package

(Note: Microdot may be in either location)

PIN CONNECTIONS



ORDERING INFORMATION

Device	Package	Shipping†
NCL30167DR2G	SOIC-10 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NCL30167

TYPICAL APPLICATION EXAMPLE

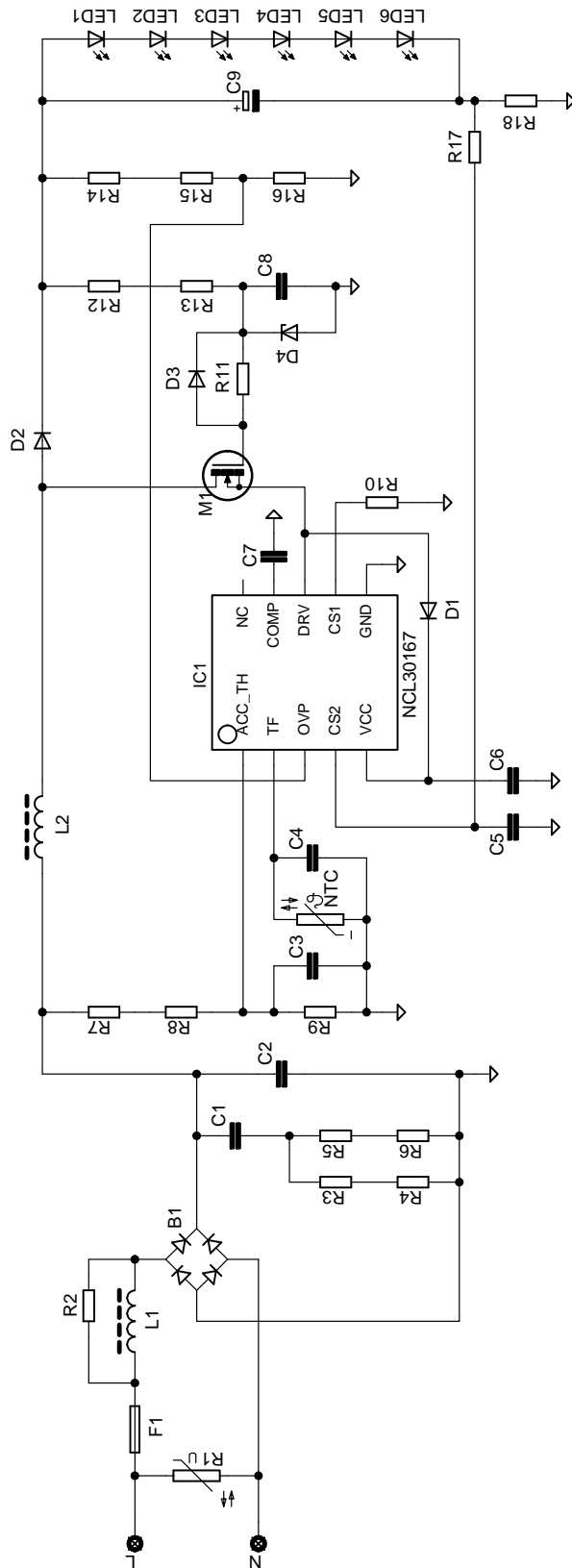


Figure 1. NCL30167 Application Schematic

PIN FUNCTION DESCRIPTION

Table 1. PIN FUNCTION DESCRIPTION

Pin Number	Pin Name	Function	Description
1	ACC_TH	Dimming Detection Input	This pin receives a portion of the AC input voltage. It is compared to an internal reference voltage in order to determine the presence of a dimmer state and the phase angle.
2	TF	Thermal Fold-back	Connecting an NTC to this pin allows linear reduction of the output current above a user programmed temperature set-point.
3	OVP	Over Voltage Protection Input	This pin receives a portion of the Boost output voltage V_{OUT} and serves to trigger an OVP fault in the event the LED string is open.
4	CS2	2 nd Current Sense Input	This pin monitors the LED load current across the R_{sense2} resistor during the off time. This pin is used to monitor the instantaneous load current for regulation loop, and to determine when the Zero Current Detection (ZCD) point is reached.
5	V_{CC}	V_{CC} Input	This positive supply pin accepts up to 20 Vdc. The supply for the device is ensured by the external diode from the source pin.
6	GND	–	The switching regulator ground
7	CS1	1 st Current Sense Input	This pin monitors the inductor current across the R_{sense1} resistor during the on-time. This pin monitors the maximum current cycle by cycle.
8	DRV	Drive for HV Switch	The Driving Pin for Source of the External High Voltage NMOS. Connect the external diode between the source and V_{CC} pin to provide the IC supply.
9	COMP	Compensation	Feedback loop compensation pin of the IC.
10	NC	Not Connected	



Table 2. MAXIMUM RATINGS

Symbol	Pin	Rating	Value	Unit
DRV	8	External NMOS Source Driving Pin	–0.3 to 20	V
		Continuous Current		
		$R_{\theta J-C}$ Steady State, $T_C = 25^\circ\text{C}$ (Note 1)	0.5	A
		$R_{\theta J-C}$ Steady State, $T_C = 100^\circ\text{C}$ (Note 1)	0.25	A
		Peak Current	–0.01/1.7	A
V_{CC}	5	V_{CC} Power Supply Voltage, V_{CC} Pin, Continuous Voltage	–0.3 to 20	V
		Power Supply Voltage, V_{CC} Pin, Continuous Voltage (Note 2)	± 30 (Peak)	mA
CS1	7	Maximum Voltage	–0.3 to 5.5	V
		Continuous Current	–1.7/0.01	A
V_{max}		Maximum Voltage on Low Power Pins (except pins 5, 7, 8)	–0.3 to 9	V
		Maximum Peak Current to Low Power Pins	± 10	mA
$R_{\theta J-A}$		Thermal Resistance Junction-to-Air	180	$^\circ\text{C/W}$
T_{JMAX}		Operating Junction Temperature	–40 to +125	$^\circ\text{C}$
$T_{STRGMAX}$		Storage Temperature Range	–60 to +150	$^\circ\text{C}$
T_{Lmax}		Lead Temperature (Soldering, 10 s)	300	$^\circ\text{C}$
MSL		Moisture Sensitivity Level	3	–
		ESD Capability, HBM model (Note 2)	3.5	kV
		ESD Capability, Machine Model (Note 2)	250	V
		ESD Capability, CDM model (Note 2)	1	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Limited by the junction temperature.
- This device contains ESD protection and exceeds the following tests:
Human Body Model 3500 V per JEDEC Standard JESD22–A114E,
Machine Model Method 250 V per JEDEC Standard JESD22–A115B,
Charged Device Model 1000 V per JEDEC Standard JESD22–C101E.
- This device contains Latch-up protection and has been tested per JEDEC JESD78D, Class I and exceeds ± 100 mA.

Table 3. ELECTRICAL CHARACTERISTICS

(For typical values $T_J = 25^\circ\text{C}$, for min/max values $T_J = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 13$ V unless otherwise noted)

Characteristics	Test Conditions	Symbol	Min	Typ	Max	Unit
SUPPLY						
Turn-on Threshold Level	V_{CC} Going Up	$V_{CC(on)}$	11.0	12.0	13.0	V
Minimum Operating Voltage, Turn-off Threshold	V_{CC} Going Down	$V_{CC(off)}$	8.2	8.8	9.4	V
Hysteresis $V_{CC(on)} - V_{CC(off)}$		$V_{CC(hyst)}$	2.8	–	–	V
V_{CC} Decreasing Level at which the Internal Logic Resets		$V_{CC(reset)}$	4.0	5.0	6.0	V
Blanking Duration on $V_{CC(off)}$		$t_{VCC(off)}$	–	10	–	μs
Blanking Duration on $V_{CC(reset)}$		$t_{VCC(reset)}$	–	10	–	μs
Internal Current Consumption of Device before Start-up	$V_{CC} = 10$ V	I_{CC1}	–	10	100	μA
Internal Current Consumption, when DRV Pin is Switching	$f_{SW} = 65$ kHz	I_{CC2}	–	1.0	1.5	mA
Internal Current Consumption, when DRV Pin is Turned-on	$V_{CS1} < 0.3$ V	I_{CC3}	–	0.9	1.1	mA

Table 3. ELECTRICAL CHARACTERISTICS (continued)(For typical values $T_j = 25^\circ\text{C}$, for min/max values $T_j = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 13\text{ V}$ unless otherwise noted)

Characteristics	Test Conditions	Symbol	Min	Typ	Max	Unit
OUTPUT OVER VOLTAGE PROTECTION						
Over Voltage Protection Thresholds	V_{OVP} Going Up V_{OVP} Going Down	$V_{OVP(off)}$ $V_{OVP(on)}$	2.9 2.6	3.0 2.7	3.1 2.8	V
Over Voltage Protection Hysteresis		$V_{OVP(hyst)}$	–	300	–	mV
Timer Duration for Over Voltage Detection		t_{OVP}	23	33	43	μs
Internal OVP Pin Pull-up Current		$I_{OVP(bias)}$	50	250	450	nA
Under Voltage Detect Threshold		V_{UVP}	0.4	0.5	0.6	V
Under Voltage Detect Propagation Delay		t_{UVP}	23	33	43	μs
LED CURRENT REGULATION LOOP						
Error Amplifier Trans-conductance		G_{EA}	85	100	115	μS
Error Amplifier Current Capability		I_{EA}	± 13	± 25	–	μA
Error Amplifier Input Offset	$T_j = 25^\circ\text{C}$	V_{EAIO}	–20	–	20	mV
Maximum Control Voltage	$V_{CS2} < 0.5\text{ V}$	$V_{COMP(max)}$	4.2	–	–	V
Minimum Control Voltage	$V_{CS2} > 1.5\text{ V}$	$V_{COMP(min)}$	–	–	0.7	V
COMP Pin Discharge Resistance		$R_{COMP(dis)}$	–	200	–	Ω
CURRENT SENSE 1 – INDUCTOR OVER CURRENT LIMITATION						
Maximum Internal Current Set-point	$V_{COMP} > 4\text{ V}$	V_{ILIM}	0.95	1.00	1.05	V
Propagation Delay from V_{Ilimit} Detection to Switch Off	$V_{CS1} > 1.2\text{ V}$	t_{delay}	–	50	90	ns
Minimum Internal Current Set-point (Dimming is Detected)	$V_{COMP} < 0.7\text{ V}$	V_{ILIM_MIN}	300	350	400	mV
Propagation Delay from Reduced V_{Ilimit} Detection to DRV Off	$V_{CS1} > 1.2\text{ V}$	t_{delay_DIM}	–	50	90	ns
Leading Edge Blanking Duration for V_{ILIM}		t_{LEB}	220	320	420	ns
Threshold for Winding Short Fault Protection Activation		$V_{CS1(stop)}$	1.42	1.50	1.58	V
Leading Edge Blanking Duration for $V_{CS(stop)}$ (Note 1)		t_{BCS}	90	120	150	ns
CURRENT SENSE 2 – ZERO CURRENT DETECTION AND LED REGULATION INPUT						
Input Pull-up Current	$V_{CS2} = 0.7\text{ V}$	$I_{CS2(bias)}$	–	1	–	μA
Internal Reference for Nominal LED Current		V_{REF}	233	250	267	mV
Lower ZCD Threshold	V_{CS2} Falling	$V_{ZCD(falling)}$	15	50	80	mV
Upper ZCD Threshold	V_{CS2} Rising	$V_{ZCD(rising)}$	30	65	95	mV
ZCD Comparator Hysteresis		$V_{ZCD(hyst)}$	–	15	–	mV
Propagation Delay from ZCD to Turn-on Internal Switch	V_{CS2} Falling	t_{DEM}	400	500	600	ns
Current Sense Threshold for CS2 Pin Open Protection		$V_{CS2(stop)}$	4.0	4.5	5.0	V
Blanking duration for ZCD Detection		$t_{ZCD(blank)}$	200	300	400	ns
ZCD Timeout		$t_{ZCD(timeout)}$	20	32	45	μs

Table 3. ELECTRICAL CHARACTERISTICS (continued)(For typical values $T_j = 25^\circ\text{C}$, for min/max values $T_j = -40^\circ\text{C}$ to $+125^\circ\text{C}$, $V_{CC} = 13\text{ V}$ unless otherwise noted)

Characteristics	Test Conditions	Symbol	Min	Typ	Max	Unit
DIMMING DETECTION						
Dimming Detection Comparator Thresholds	V_{ACCTH} Going Up V_{ACCTH} Going Down	V_{ACCTH_H} V_{ACCTH_L}	0.400 0.300	0.450 0.350	0.500 0.400	V
Dimming Detection Comparator Hysteresis		V_{ACCTH_Hyst}	–	100	–	mV
Dimming Detection Comparator Delay	$V_{ACCTH} = V_{ACCTH_H} + 0.1\text{ V}$	t_{DIM_D}	40	70	90	μs

ON-TIME GENERATOR

Maximum On Time	$V_{COMP} = 4.2\text{ V}$	t_{ONmax}	15	18	22	μs
On Time	$V_{COMP} = 2.5\text{ V}$	t_{ON}	8.0	9.5	11.0	μs
Minimum On Time	$V_{COMP} = 0.7\text{ V}$	t_{ONmin}	–	0.6	1.2	μs

THERMAL FOLDBACK

TF Pin Voltage at which Thermal Fold-back Starts (V_{REF} is Decreased)		$V_{TF(start)}$	0.94	1.00	1.06	V
TF Pin Voltage at which Thermal Fold-back Reduces V_{REF} to 10% V_{REF}		$V_{TF(10\%)}$	0.45	0.5	0.55	V
Current Source for Direct NTC Connection	$V_{TF} = 0\text{ V}$	I_{TF}	80	85	90	μA
Blanking Duration for TF Detection after Start-up	$V_{TF} < V_{TF(5\%)}$	$t_{TF(blank)}$	250	300	350	μs

INTERNAL TEMPERATURE SHUTDOWN

Temperature Shutdown (Note 1)	T_j Going Up	T_{TSD}	135	150	165	$^\circ\text{C}$
Temperature Shutdown Hysteresis (Note 1)	T_j Going Down	$T_{TSD(HYS)}$	–	30	–	$^\circ\text{C}$

INTERNAL DRIVING SWITCH

On State Resistance of the Driving NMOS	$I_{DRV} = 500\text{ mA}$, $T_j = 25^\circ\text{C}$	$R_{L,DS,on}$	–	3.5	4.5	Ω
Maximum Drain to Source Voltage of the Driving NMOS (Note 1)		$V_{L,DS,max}$	30	–	–	V
Maximum Off State Leakage Current	$V_{DRAIN} = 19\text{ V}$	I_{DSS}	–	–	5	μA
Turn-on Time, 90 to 10 % of V_{DRV}	$I_{DRV} = 500\text{ mA}$	t_{on}	–	10	–	ns
Turn-off Time, 10 to 90 % of V_{DRV}	$I_{DRV} = 500\text{ mA}$	t_{off}	–	30	–	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Guaranteed by design.

TYPICAL CHARACTERISTIC

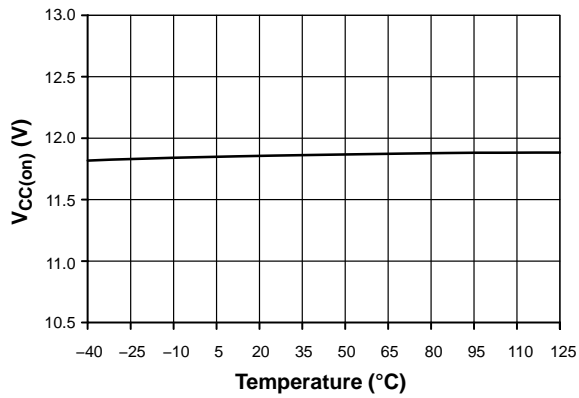


Figure 3. Turn-On Threshold Level, V_{CC(on)}

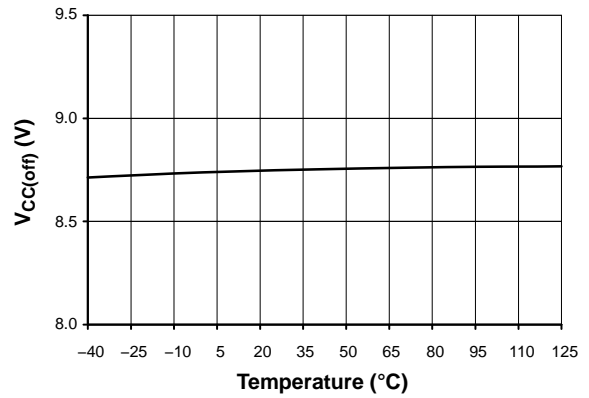


Figure 4. Minimum Operating Voltage, V_{CC(off)}

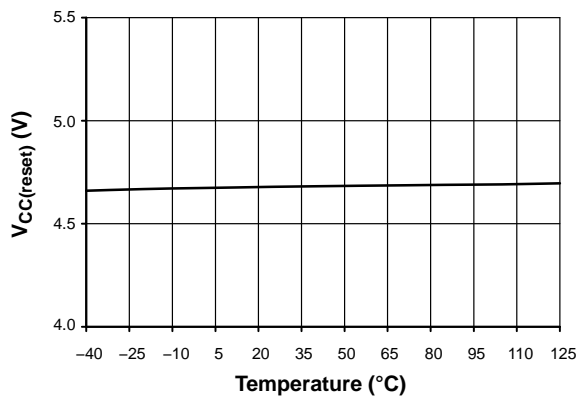


Figure 5. V_{CC} Decreasing Level at which the Internal Logic Resets, V_{CC(reset)}

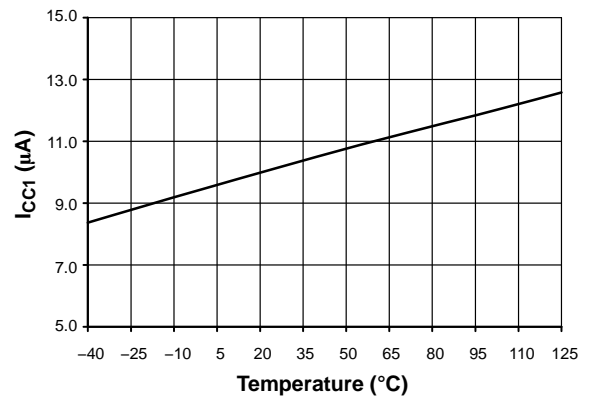


Figure 6. Internal Current Consumption before Start-Up, I_{CC1}

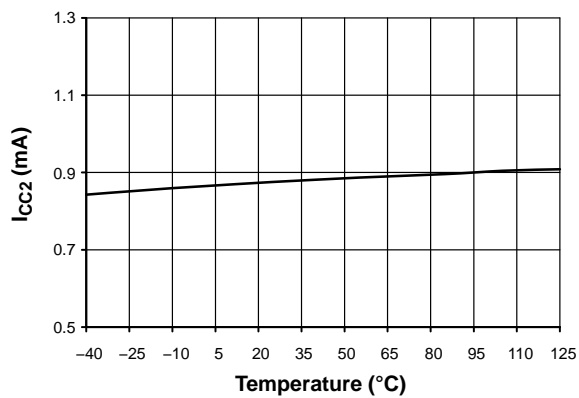


Figure 7. Internal Current Consumption when DRV Pin is Switching, I_{CC2}

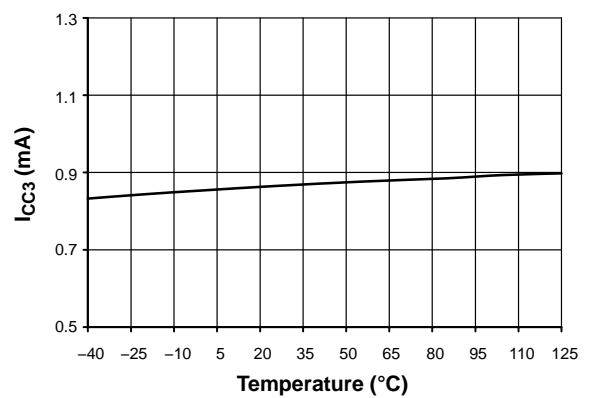


Figure 8. Internal Current Consumption when DRV Pin is Turned-On, I_{CC3}

TYPICAL CHARACTERISTIC

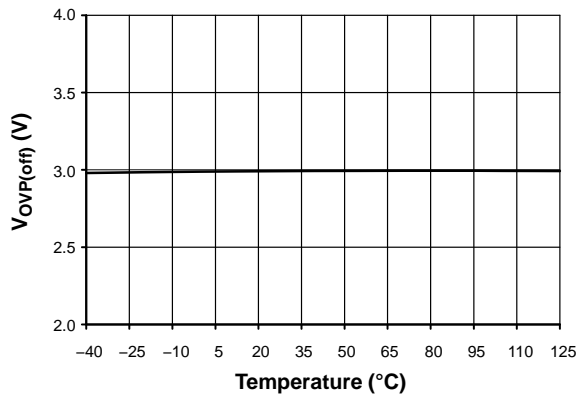


Figure 9. Over-Voltage Protection Threshold (V_{OVP} Going Up), V_{OVP(off)}

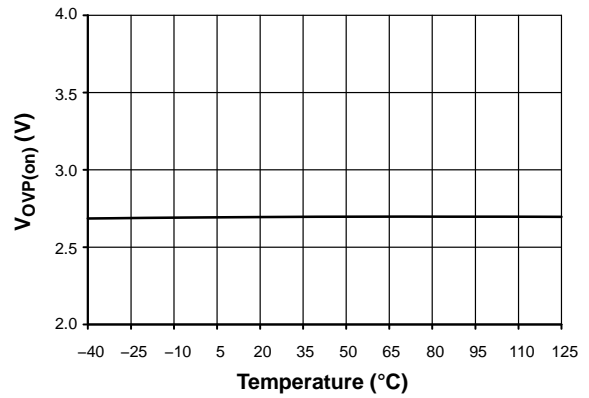


Figure 10. Over-Voltage Protection Threshold (V_{OVP} Going Down), V_{OVP(on)}

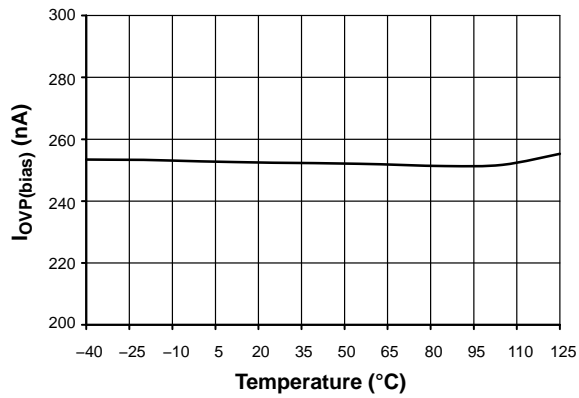


Figure 11. Internal OVP Pin Pull-Up Current, I_{OVP(bias)}

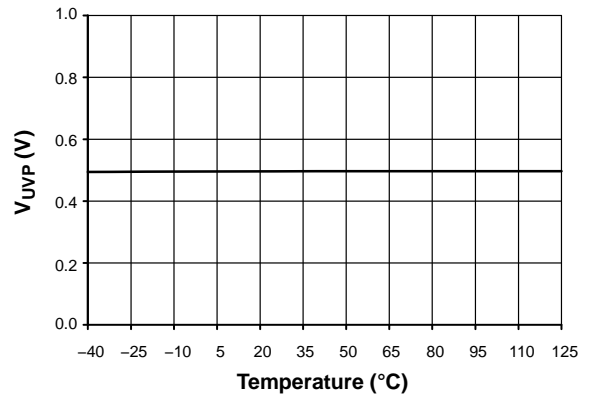


Figure 12. Under-Voltage Detect Threshold, V_{UVP}

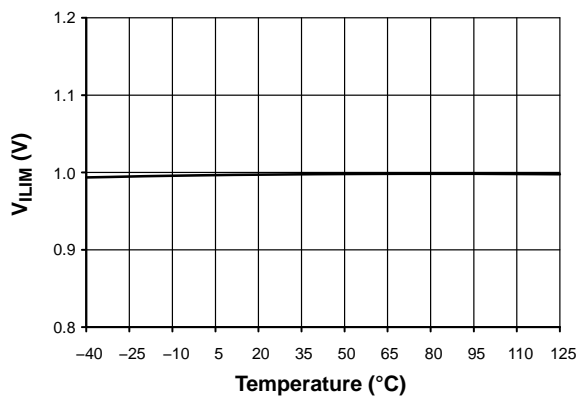


Figure 13. Maximum Internal Current Set-Point, V_{ILIM}

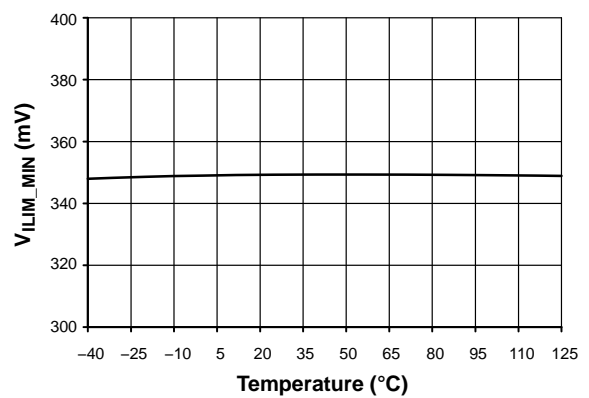


Figure 14. Minimum Internal Current Set-Point, V_{ILIM_MIN}

TYPICAL CHARACTERISTIC

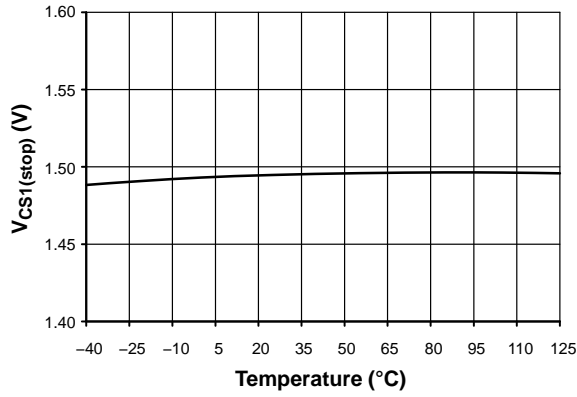


Figure 15. Threshold for Winding Short Fault Protection Activation, $V_{CS1(stop)}$

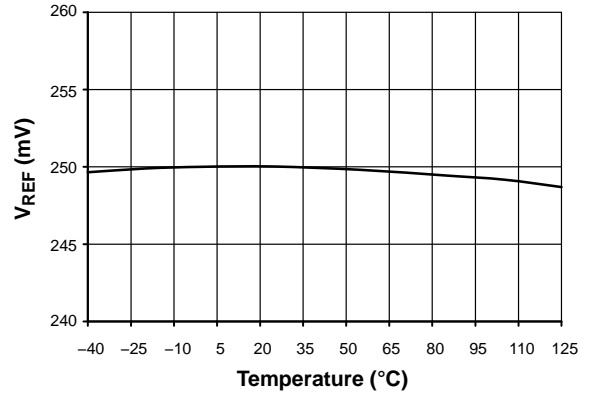


Figure 16. Internal Reference for Nominal LED Current, V_{REF}

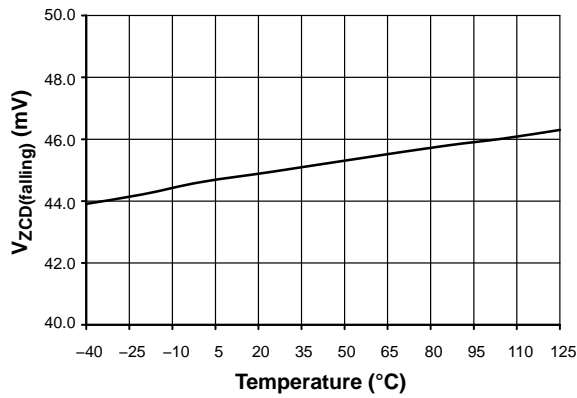


Figure 17. Lower ZCD Threshold, $V_{ZCD(falling)}$

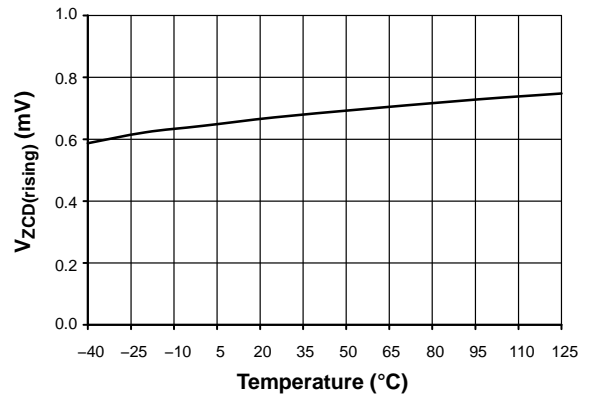


Figure 18. Upper ZCD Threshold, $V_{ZCD(rising)}$

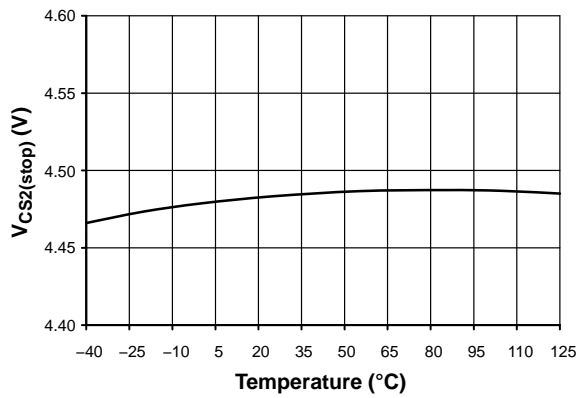


Figure 19. Current Sense Threshold for CS2 Pin Open Protection, $V_{CS2(stop)}$

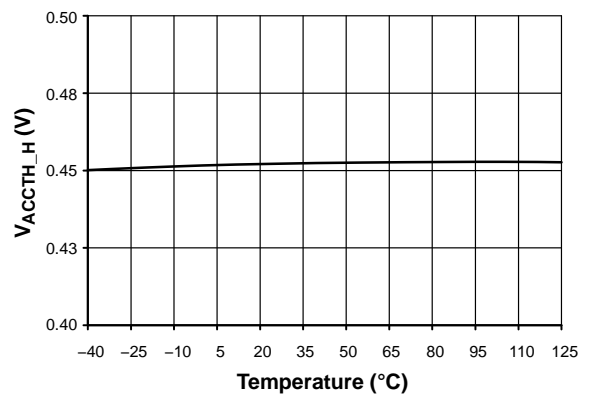


Figure 20. Dimming Detection Comparator Threshold, V_{ACCTH} Going Up, V_{ACCTH_H}

TYPICAL CHARACTERISTIC

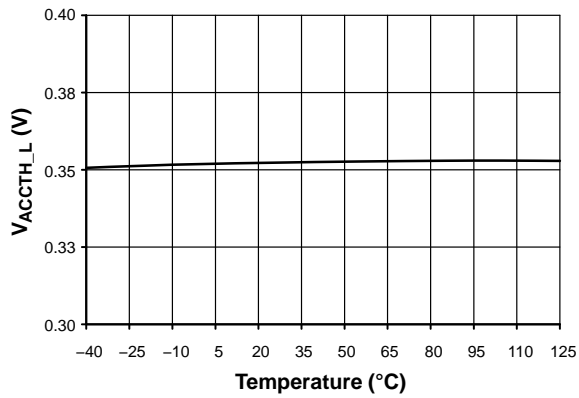


Figure 21. Dimming Detection Comparator Threshold, V_{ACCTH} Going Down, V_{ACCTH_L}

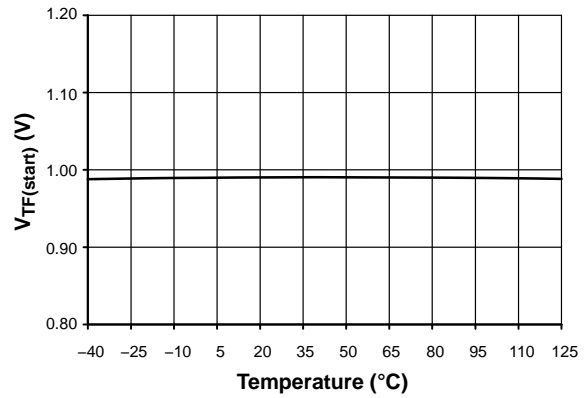


Figure 22. TF Pin Voltage at which Thermal Fold-Back Starts, $V_{TF(start)}$

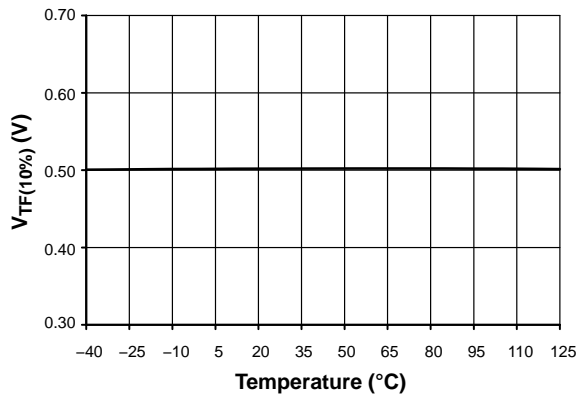


Figure 23. TF Pin Voltage at which Thermal Fold-Back Reduces V_{REF} to 10%, $V_{TF(10\%)}$

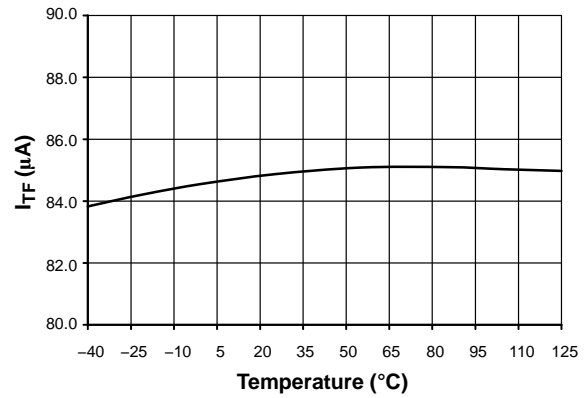


Figure 24. Current Source for Direct NTC Connection, I_{TF}

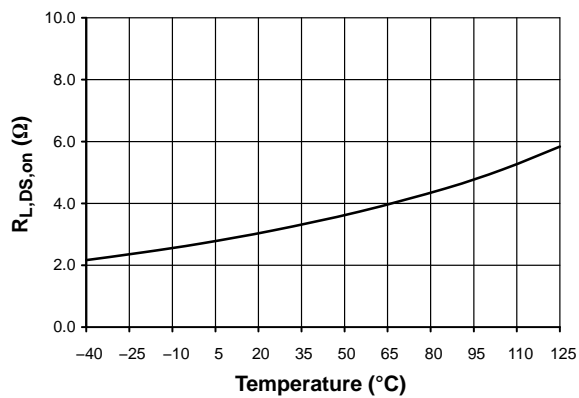


Figure 25. On-State Resistance of the Driving NMOS, $R_{L,DS,on}$

TYPICAL CHARACTERISTIC

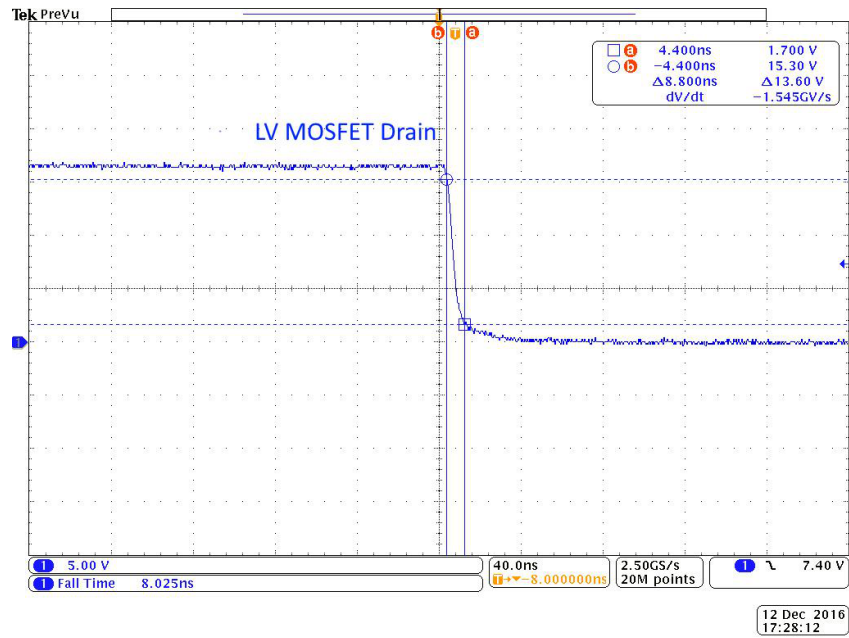


Figure 26. Typical On-Time of the Internal Driving Switch

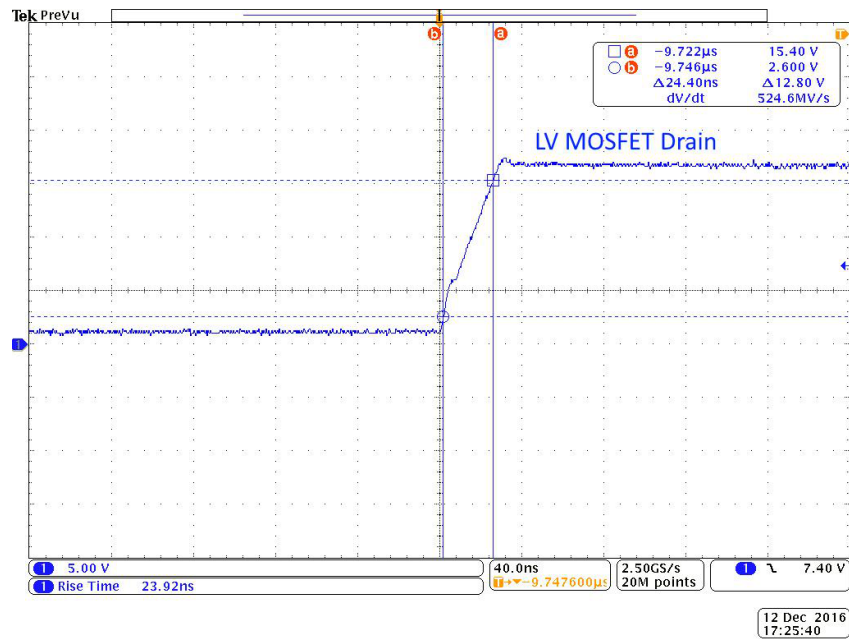


Figure 27. Typical Off-Time of the Internal Driving Switch

APPLICATION INFORMATION

Functional Description

NCL30167 uses a Constant On-time Boost architecture in order to target a unity power factor, when no dimming is detected. The cascoded drain architecture shown in Figure 28, where M_{HV_ext} is the High Voltage Cascode NMOS, allows a simple implementation of a V_{CC} supply by including a diode D_{VCC} , external to the switcher IC,

between the DRAIN pin and capacitor C_{VCC} . Thanks to the cascoded drain architecture, the startup time is very fast (typ < 100 ms). Unlike a traditional asynchronous boost architecture, the cascoded architecture uses two MOSFETS. The low voltage MOSFET $M_{LV_int.}$, which is housed inside the IC, drives the external High Voltage NMOS M_{HV_ext} via the DRV pin.

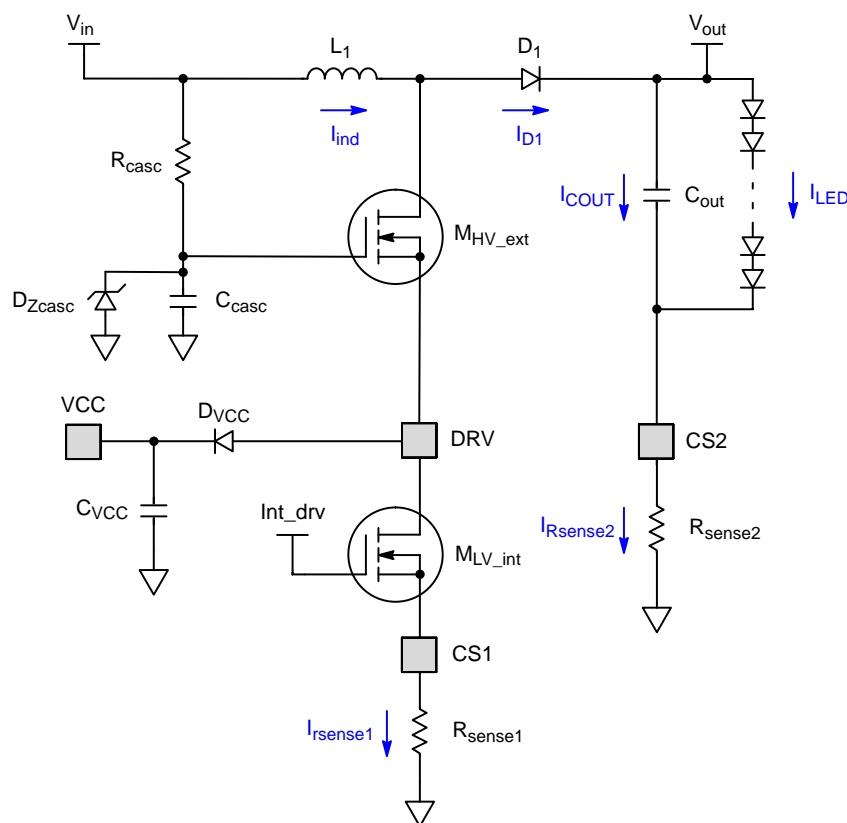


Figure 28. Cascode Architecture

The NCL30167 operates in Critical Conduction Mode (CrM) under all working conditions, regulating the average current flowing through the string of LEDs whether the dimmer is present or not.

The ACC_TH pin senses a scaled down input voltage (V_{in}) and by comparing it to an internal reference voltage named V_{ACC_TH} it provides a digital signal DIM/DIMb that contains the amount of dimming information. DIM/DIMb is

processed then by a circuit block named “Vref processing”, which provides analog signal Vref. The reference voltage named Vref serves for the LED current regulation loop. The LED current regulation loop is working for all conduction angles, it is then possible by programming the Vref processing circuit block to get the desired dimming curve as depicted in Figure 30.

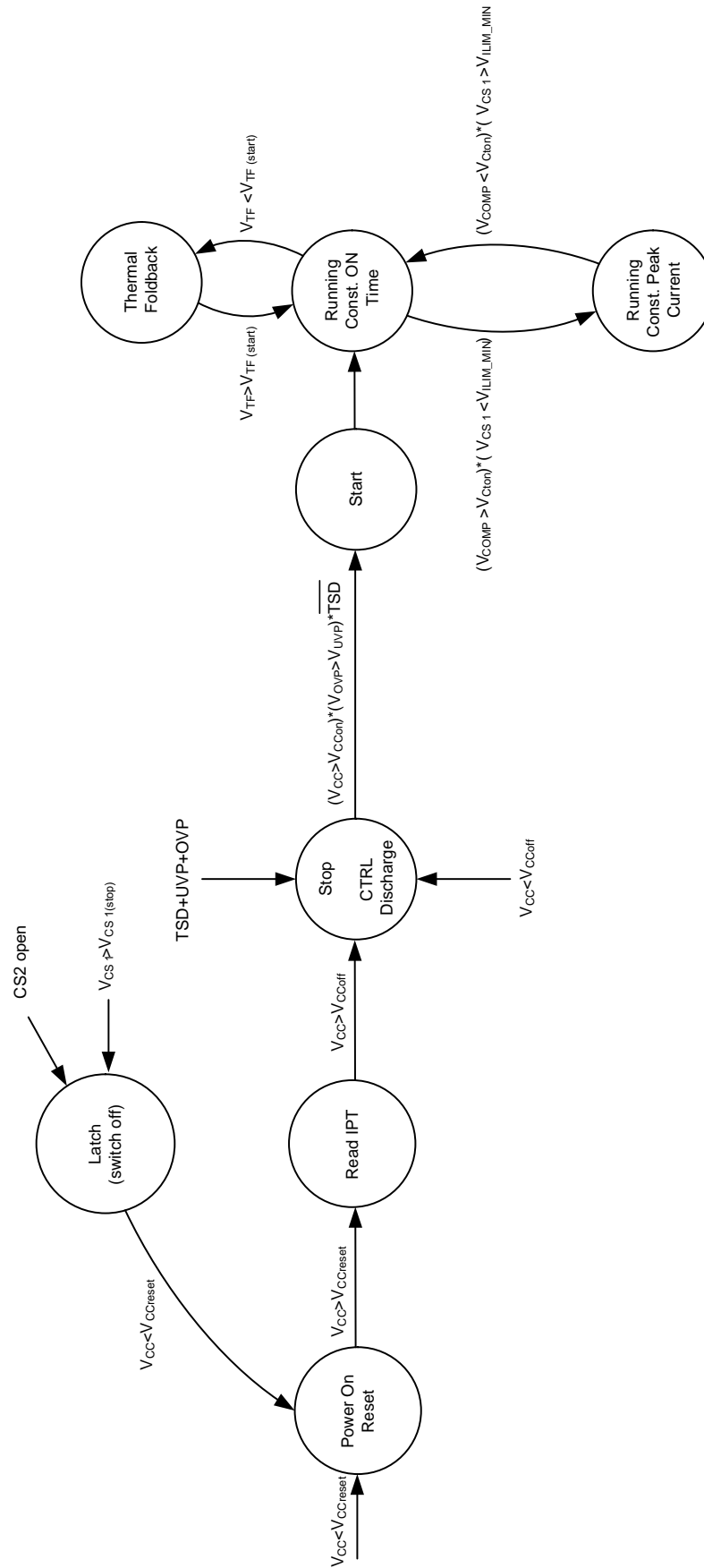


Figure 29. Operating Status Diagram of the Device

Critical Conduction Mode

By looking at Figure 28 it can be seen that, the current $I_{R_{sense1}}$ flowing through the external resistor R_{sense1} , connected between pin CS1 and GND, is the same as the inductor current I_{ind} plus current spikes associated with the turning on or turning off of M_{LV_int} NMOS FET. The inductor current information carried by the pin CS1 is used for the inductor peak current limitation. This voltage V_{CS1} is used to generate a reset signal (OCP_RST) resulting from having reached the inductor maximum peak current controlled by V_{ILIM_MIN} reference voltage. If the maximum peak inductor current is not reached it is the second branch that takes care of the reset signal (RST) indicating the end of the on-time. The second branch monitors the off-time current information at current sense input CS2. The CS2 sensing is inhibited during the MOSFET on-time.

As shown in Figure 2, the second branch voltage is an image of the off-time inductor current. It is sent to the input of an OTA and by comparing to a reference voltage (V_{REF}) a control voltage is generated at the COMP pin. The COMP pin voltage is proportional to the average LED current. It is compared to a constant on-time ramp voltage generated by charging the capacitor C_{TON} by a constant current I_{TON} . The output of the comparator generates constant on-time reset signal (RST). This process represents the “constant t_{on} average LED regulation loop” which, when steady state is reached, ensures that:

$$I_{LEDavg} = \frac{V_{REF}}{R_{sense2}} \quad (\text{eq. 1})$$

There is one more condition to end the on-time cycle. The power MOSFET is turned-off only under a condition that the inductor peak current reaches a level set by the reference voltage named V_{ILIM_MIN} . Minimum input current is maintained by switching in Constant Peak Current mode. When a dimmer is present this feature helps to avoid the leakage current of the dimmer from charging the C_{in} capacitor. At the same time this feature sets a minimum input current to avoid the current loop cut off when the triac dimming is applied.

The reset signal (RST or OCP_RST) indicates an end of the on-time and a start of the off-time. Once the off-time has started, the CS2 pin senses the inductor off-time current across R_{sense2} . It is compared to a reference voltage V_{ZCD} in order to generate a zero-crossing signal (ZCD) that in turn is processed by the clock generation block. The generated clock pulse triggers a start of the new on-time cycle.

LED Current Regulation and Dimming Curve

As long as the max peak current limitation is not exceeded or a thermal foldback condition is present, the average LED current regulation loop is controlled by the OTA via Equation 1 and Triac Dimming Curve of Figure 30.

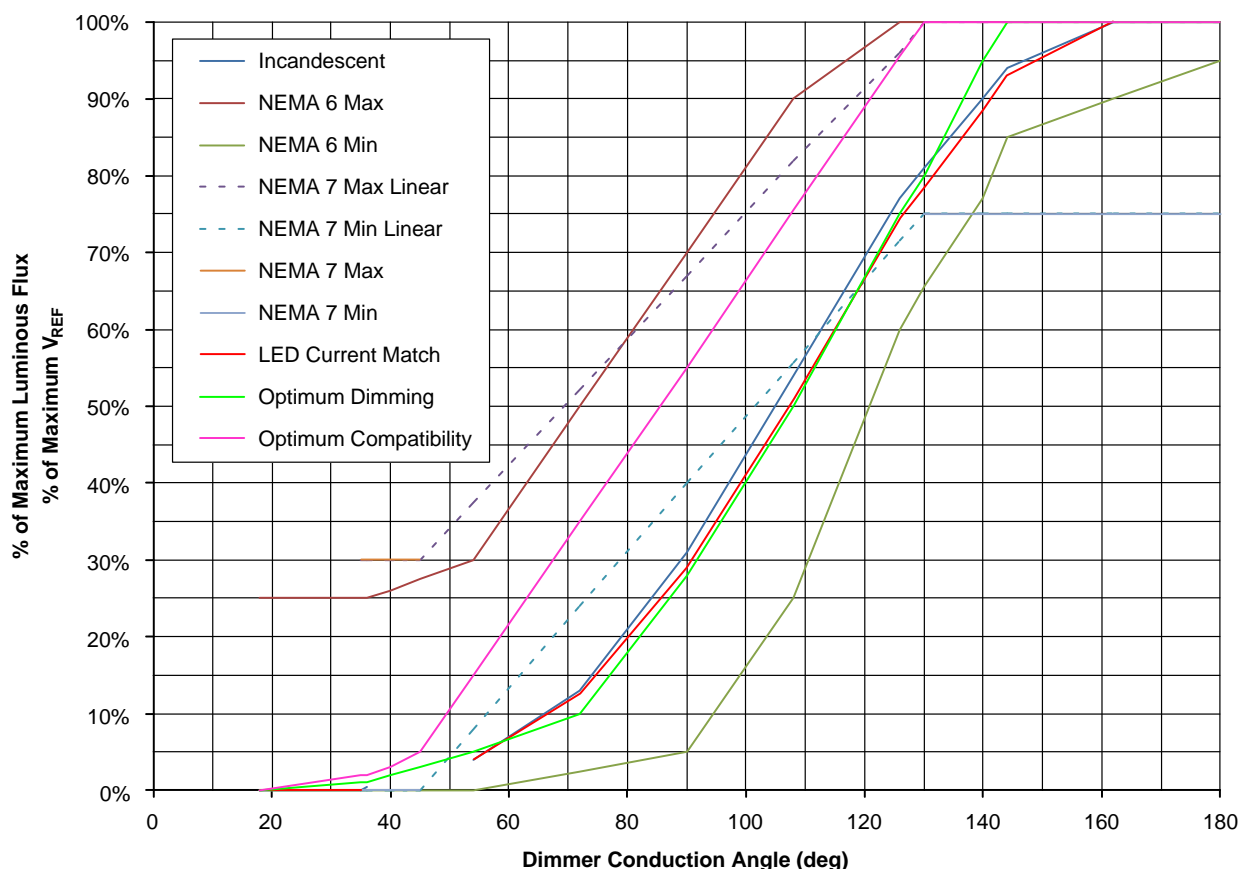


Figure 30. Triac Dimming Curve Digitally Generated

For example if $R_{\text{sense}2} = 20\ \Omega$ and $V_{\text{REF}} = 0.5\ \text{V}$ it gives $I_{\text{LED}} = 25\ \text{mA}$. The circuit block named V_{REF} processing which can be seen in Figure 2 will be programmed for the

optimum compatibility acceleration curve by default (see Figure 30) with an option of the optimum dimming acceleration curve.

Table 4. COORDINATES OF DIMMING CURVE PROGRAMMING POINTS

Dimmer Conduction Angle (Deg)	Optimum Dimming $V_{\text{REF}}/V_{\text{REF,max}}$	Optimum Compatibility $V_{\text{REF}}/V_{\text{REF,max}}$
18	0.0%	0.0%
35	1.0%	2.0%
36	1.0%	2.0%
40	2.0%	3.0%
45	3.0%	5.0%
54	5.0%	15.0%
72	10.0%	35.0%
90	28.0%	55.0%
108	50.0%	75.5%
126	75.0%	95.5%
130	80.0%	100.0%
140	95.0%	100.0%
144	100.0%	100.0%
162	100.0%	100.0%
180	100.0%	100.0%

To regulate an average LED current in a single stage architecture the instantaneous LED current can have as much as $\pm 50\%$ ripple component (this ripple component depends on the value of C_{out} capacitor and LED string dynamic resistance). The OTA must work linearly while a voltage with ripple is applied. The transconductance (G_m) value is set as low as $100\ \mu\text{S}$ and the minimal output current capability is at $\pm 40\ \mu\text{A}$ to ensure the OTA linear operation, without entering the saturation level.

Dimming Presence Sensing

The conduction angle of the dimmer is sensed through pin ACC_TH. The rectified and dimmed V_{in} voltage (see Figure 1) appears on pin ACC_TH divided by the resistor bridge composed of $R_{\text{acc_top}}$ and $R_{\text{acc_bot}}$. The ACC_TH voltage is equal to:

$$V_{\text{ACC_TH}} = K_{\text{acc}} \cdot V_{\text{in}} \quad (\text{eq. 2})$$

where:

$$K_{\text{acc}} = \frac{R_{\text{acc_bot}}}{R_{\text{acc_bot}} + R_{\text{acc_top}}} \quad (\text{eq. 3})$$

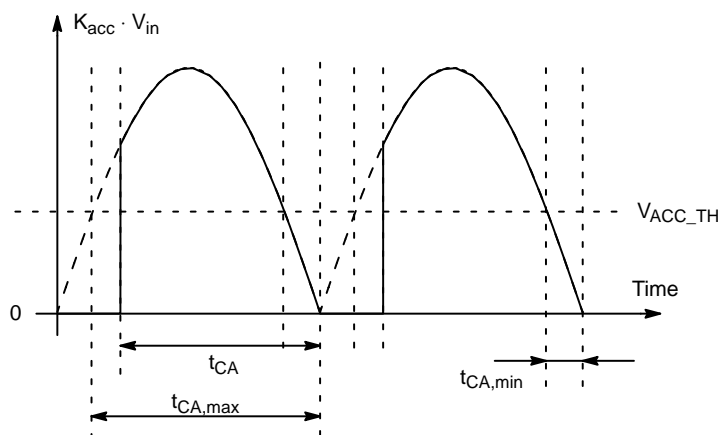


Figure 31. ACC_TH Pin Waveforms and Max/Min Detectable Dimmer Conduction Angles

Voltage sensed at the ACC_TH pin is compared to the V_{ACC_TH} reference voltage (see Figure 31) in order to generate a digital signal (DIM/DIMbar) (see Figure 2 and Figure 32). The DIM/DIMbar signal is used as the input of the block named “Vref processing block”. Every half period of the mains voltage, the “Vref processing block” computes and holds the dimmer duty cycle and sets the corresponding V_{REF} voltage.

Unless the minimum peak current at CS1 pin reaches the V_{ILIM_MIN} level the internal power MOSFET connected

between DRAIN and CS pins is kept open to avoid a leakage current of the dimmer from charging the C_{in} capacitor (see Figure 1) and providing a low impedance path for “SMART” dimmer operation.

CA is the Dimmer Conduction Angle expressed in degrees and can be calculated based on the Dimmer Conduction Time t_{CA} (see Figure 32) and the AC mains frequency f_{mains} described in the following formula:

$$CA = 360 \cdot t_{CA} \cdot f_{mains} \quad (\text{eq. 4})$$

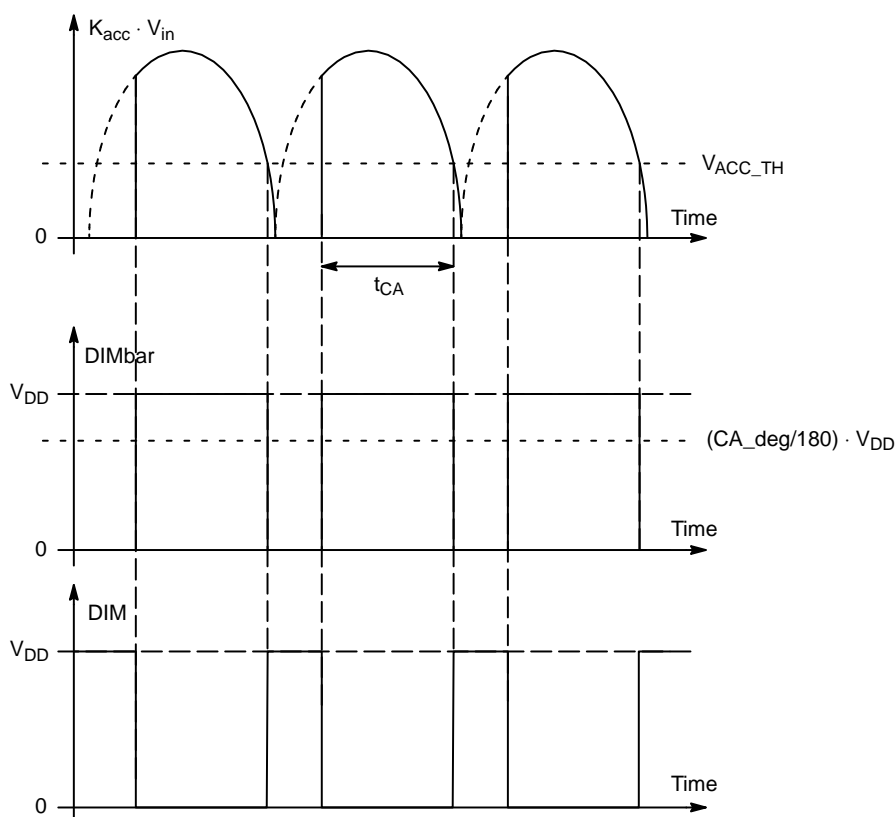


Figure 32. Dimming Waveforms

Detailed Description of the V_{REF} Processing

The conduction angle is obtained by the digital division of the sampled values of the conduction time and the period. The conduction time is counted by the timer A over the both periods of mains as the period of mains. This type of sensing decreases the dimming system sensitivity to the asymmetry of the dimming triac and reduces flickering. The conducting angle is obtained as the ratio of Timer A (conduction time) and Timer B (the mains period). Please refer to Figure 33 and Figure 34.

$$CA = \frac{2 \cdot T_{on}}{2 \cdot T} \quad (\text{eq. 5})$$

The additional IIR filters and the conduction angle lockout for 32 cycles of the rectified mains signal helps to reduce flickering caused by the differing leading edges and quantization error of the A/D conversion at TF pin and CA measurement.



Figure 34. Time Diagram of the Implemented Conduction Angle Measurement

The minimum current set-point feature is implemented. It starts play a role in case when the V_{ref} is so small that the current set-point observed at CS1 pin is below the V_{ILIM_MIN} level. Then the regulation loop requirement is ignored and higher level of current set-point V_{ILIM_MIN} is

applied. This feature sets the minimum current to avoid the current loop cut off when the triac dimming is applied. This feature increases the compatibility with the most of the triac dimmers.

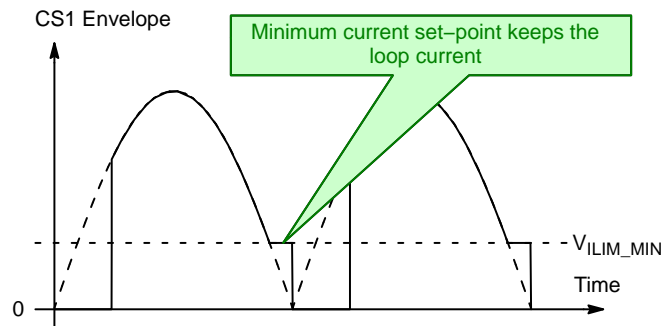


Figure 35. The Minimum Current Set-Point Effect to Keep the Loop Current

Table 5. OPERATING MODES AND PROTECTION MODES

Event	Timer Protection	Next Device Status	Release to Normal Operation Mode
Overcurrent $V_{ILIM} = 1.0 \text{ V}$	N/A	Normal Operation	N/A
Reduced Peak Current $V_{ILIM_MIN} = 0.35 \text{ V}$	N/A	Normal Operation	N/A
Winding Short $V_{sense1} > V_{CS1(stop)}$	4 Consecutive Pulses	Latch	$V_{CC} < V_{CC(reset)}$
Low Supply $V_{CC} < V_{CC(off)}$	10 μs Timer	Device Stops	$V_{CC} > V_{CC(on)}$
Thermal Fold-back Event $V_{OTP} < V_{TF(start)}$	Immediate Reaction	Reduced Output Current, Thermal Fold-back	$V_{OTP} > V_{TF(start)}$
Output Overvoltage $V_{OVP} > V_{OVP(off)}$	20 μs Timer	Device Stops	$V_{OVP} < V_{OVP(on)}$ $V_{CC} > V_{CC(on)}$
Overvoltage Pin Shorted to GND $V_{OVP} < V_{UVP}$	Immediate Reaction	Device Stops	$V_{CC} < V_{CC(reset)}$
Internal TSD	10 μs Timer	Device Stops	$(V_{CC} > V_{CC(on)}) \& \text{TSDb}$

20

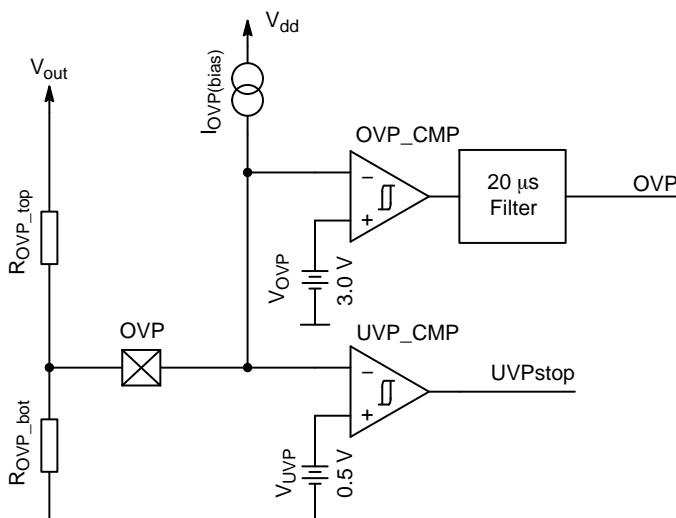


Figure 37. Overvoltage Protection Circuit

Thermal Fold-Back

The thermal fold-back circuit reduces the current supplying to the LED string if the temperature monitored by an external NTC resistor is too high.

The current is reduced down to 0% of its nominal value. The thermal fold-back starting temperature depends on the NTC resistor value selected by the power supply designer.

The TF pin allows the direct connection of an NTC. When the TF pin voltage V_{TF} drops below $V_{TF(start)}$, the internal reference for the constant current control V_{REF} is decreased proportionally to V_{TF} . When V_{TF} reaches $V_{TF(10\%)}$, V_{REF} is

set to V_{REF10} , corresponding to 10% of the required output current. If V_{TF} drops below $V_{TF(10\%)}$ the switching regulator still reduces the V_{REF} . If V_{REF} drops below the 5% of its required value then the switching regulator enters the stop mode.

The thermal fold-back and OTP thresholds correspond roughly to the following resistances:

- Thermal fold-back starts when $R_{NTC} \leq 11.76 \text{ k}\Omega$.
- Thermal fold-back sets the 10% of V_{REF} when $R_{NTC} \leq 5.88 \text{ k}\Omega$.

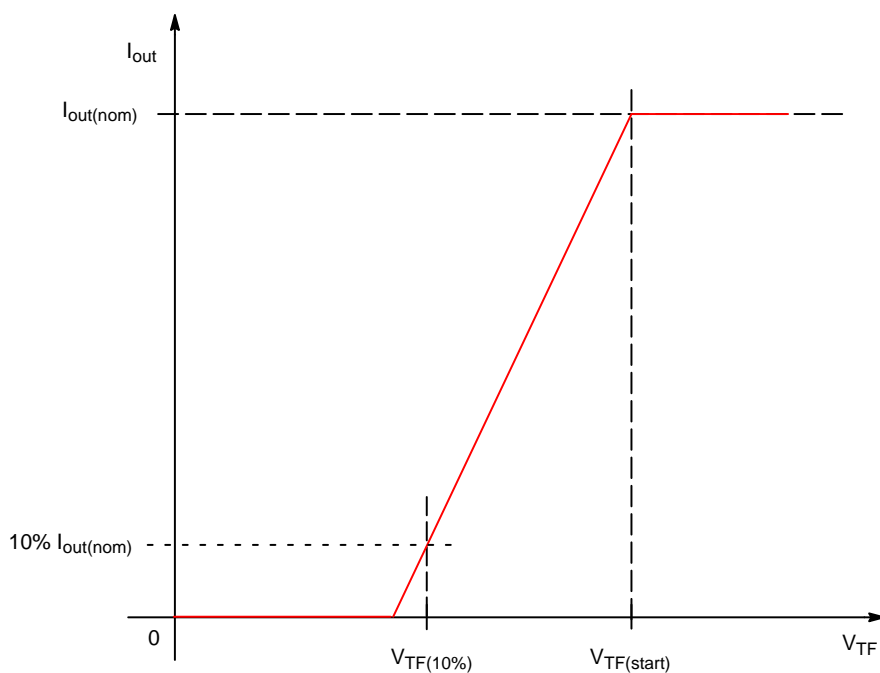


Figure 38. Output Current Reduction vs. TF Pin Voltage

At startup, when V_{CC} reaches $V_{CC(on)}$, the TF pin sensing is blanked for at least 300 μs in order to allow the TF pin voltage to reach its nominal value if a filtering capacitor is connected to the TF pin. This is to avoid flickering of the LED light in case of over temperature or noise coupled to TF pin. The maximum value of OTP pin capacitor is given by

the following formula (The standard start-up condition is considered and the NTC current is neglected):

$$C_{TF \text{ max}} = \frac{t_{TF(Blank)min} \cdot I_{TF \text{ min}}}{V_{TF(start)max}} \quad (\text{eq. 6})$$

$$= \frac{200 \cdot 10^{-6} \cdot 80 \cdot 10^{-6}}{1.06} \text{ F} = 15.1 \text{ nF}$$

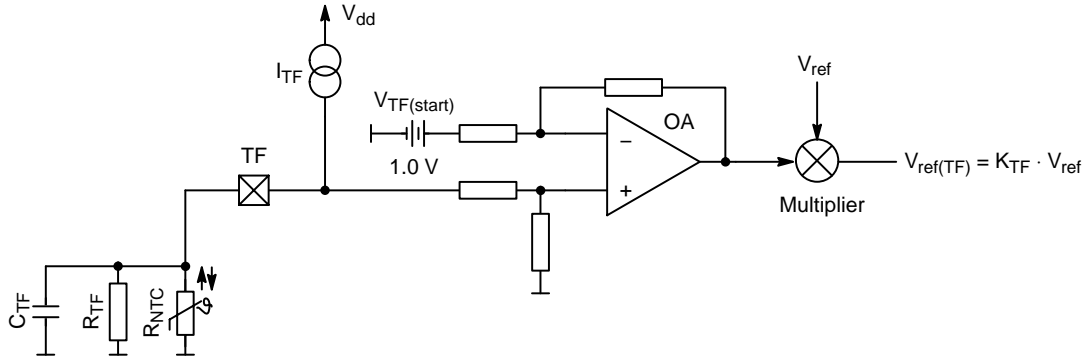


Figure 39. Thermal Fold-Back Circuitry

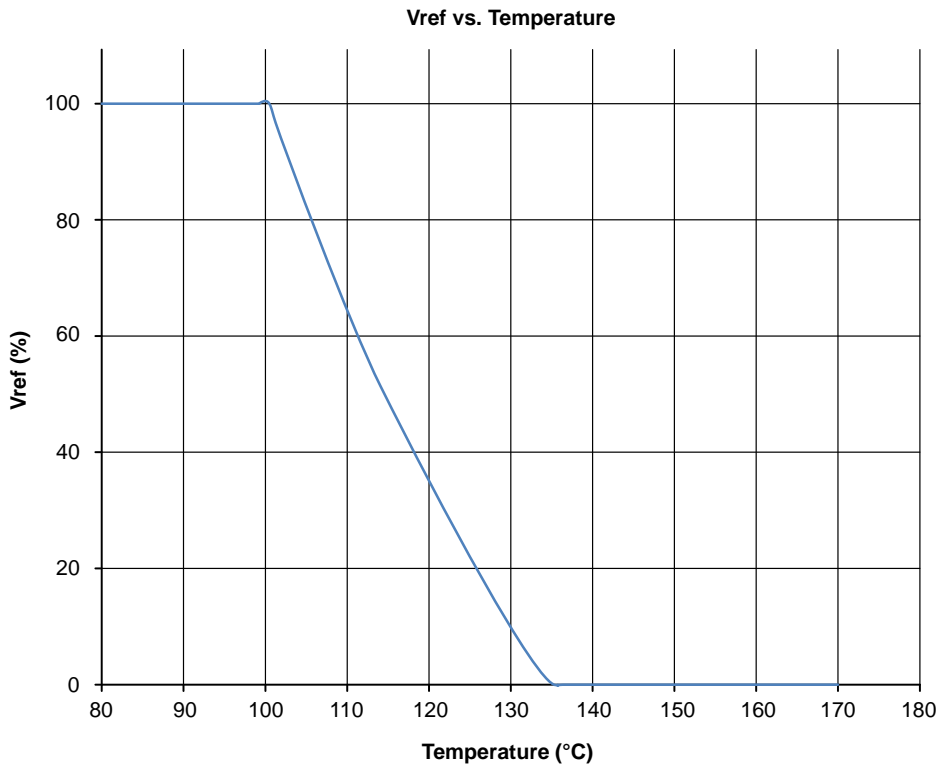


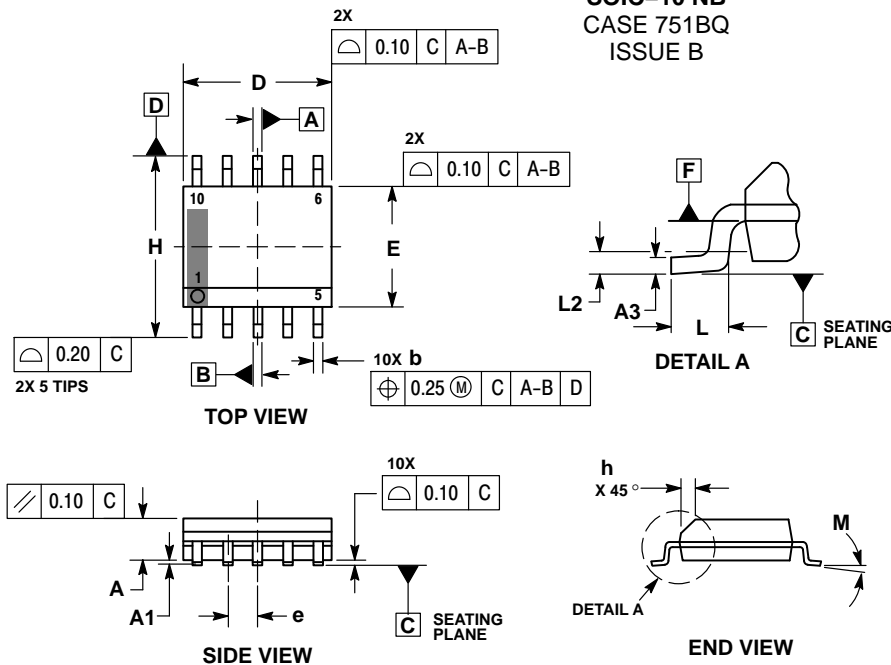
Figure 40. Typical Thermal Fold-Back Characteristics when the 330 kΩ NTC and 39 kΩ Parallel Resistor are Connected to TF Pin

Temperature Shutdown

The NCL30167 includes a temperature shutdown protection with a trip point typically at 150°C and the typical hysteresis of 30°C. When the temperature rises above the high threshold, the switcher stops switching

instantaneously, and goes to the stop mode with low power consumption. Specific blocks are still powered from the V_{CC} supply to keep the TSD information. When the temperature falls below the low threshold, the device restarts. See the status diagrams at the Figure 29.

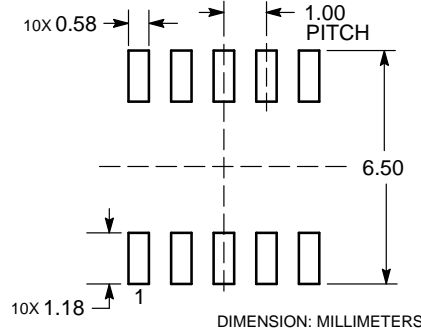
PACKAGE DIMENSIONS

SOIC-10 NB
CASE 751BQ
ISSUE B

NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.10mm TOTAL IN EXCESS OF 'b' AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15mm PER SIDE. DIMENSIONS D AND E ARE DETERMINED AT DATUM F.
5. DIMENSIONS A AND B ARE TO BE DETERMINED AT DATUM F.
6. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT ON THE PACKAGE BODY.

DIM	MILLIMETERS	
	MIN	MAX
A	1.25	1.75
A1	0.10	0.25
A3	0.17	0.25
b	0.31	0.51
D	4.80	5.00
E	3.80	4.00
e	1.00 BSC	
H	5.80	6.20
h	0.37 REF	
L	0.40	0.80
L2	0.25 BSC	
M	0°	8°

RECOMMENDED
SOLDERING FOOTPRINT*

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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